

S2A THRU S2M

SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS

FORWARD CURRENT: 2.0 AMPERE

<http://www.njzrg.com>

FEATURES

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Low forward voltage drop
- Plastic package has Underwriters Laboratory
Flammability Classification 94V-O
- High temperature soldering : 260°C /10 seconds at terminals

MECHANICAL DATA

Case: Molded plastic, DO-214AA(SMB)

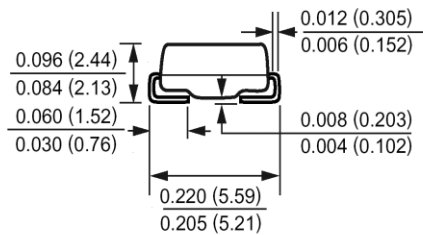
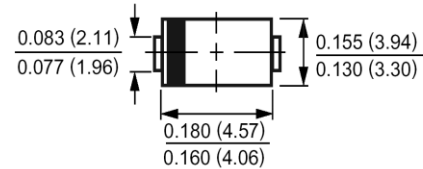
Terminals: Solder plated, solderable per MIL-STD-750,
method 2026 guaranteed

Polarity: Color band denotes cathode end

Packaging: 12mm tape per EIA STD RS-481

Weight: 0.003 ounce, 0.093 gram

DO214-AA(SMB)



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	S2A	S2B	S2D	S2G	S2J	S2K	S2M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_L=90$	$I_{(AV)}$	2.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	50							Amp
Maximum Forward Voltage at 2.0A	V_F	1.15							Volts
Maximum Reverse Current at $T_A=25$ at Rated DC Blocking Voltage $T_A=125$	I_R	5.0 125							μ Amp
Typical Junction Capacitance (Note 1)	C_J	30							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	16							/W
Maximum Reverse Recovery Time (Note 3)	T_{RR}	2.5							μ S
Operating Junction Temperature Range	T_J	-55 to +150							
Storage Temperature Range	T_{stg}	-55 to +150							

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal resistance from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas

3- Reverse Recovery Test Conditions : $I_F=0.5A$, $I_R=1A$, $I_{RR}=0.25A$.

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RATINGS AND CHARACTERISTIC CURVES

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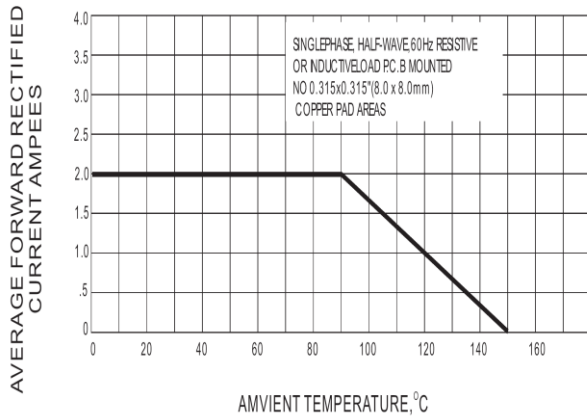


Fig. 3-MAXIMUM AVERAGE FORWARD CURRENT RATING

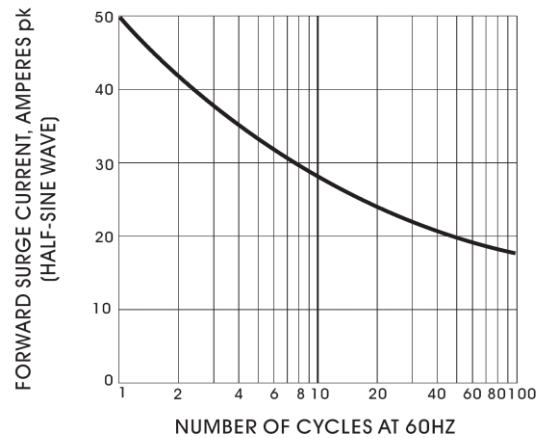


Fig. 2-MAXIMUM OVERLOAD SURGE-CURRENT

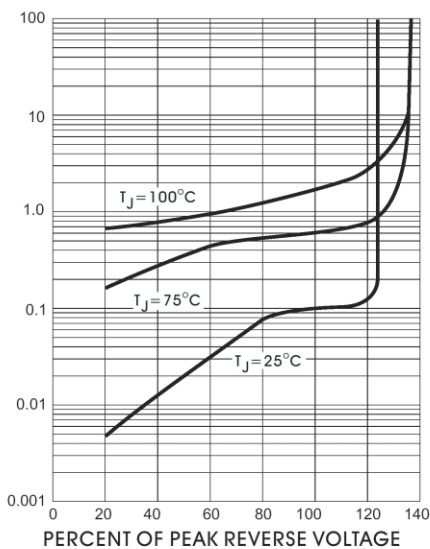


Fig. 3- TYPICAL REAK REVERSE CHARACTERISTICS

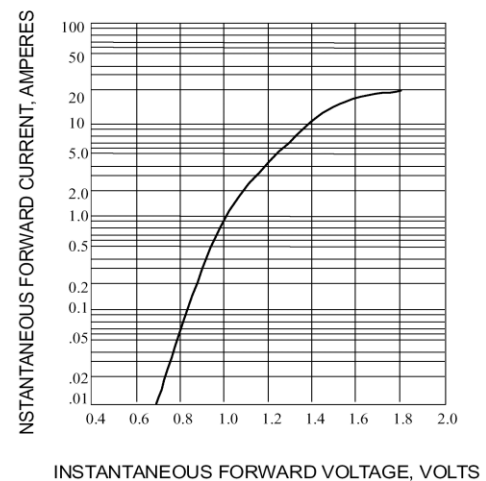


Fig. 4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

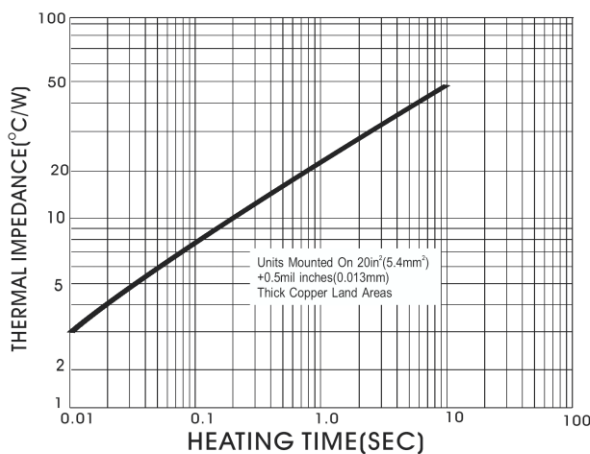


Fig. 5- TRANSIENT THERMAL IMPEDANCE

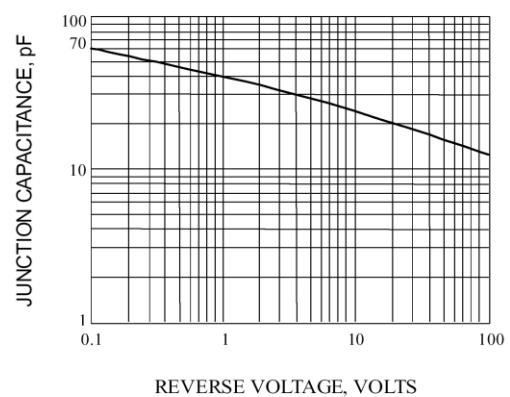


Fig. 6-TYPICAL JUNCTION CAPACITANCE